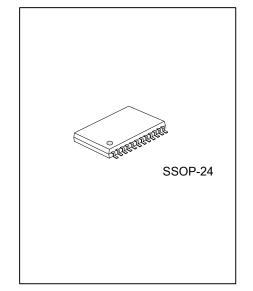
UNISONIC TECHNOLOGIES CO., LTD

L16B06 Preliminary CMOS IC

16-BIT CONSTANT CURRENT LED DRIVER

■ DESCRIPTION

The **L16B06** is a constant-current sink driver specifically designed for LED display applications. The device incorporates shift registers, data latches, and constant current circuitry on the silicon CMOS chip. The maximum output current value of all 16 channels is adjustable by a single external resistor.



■ FEATURES

*Constant-current outputs: 3mA to 60mA adjustable by one external resistor

*Maximum output voltage: 17V
*Maximum clock frequency: 25MHz
*Power supply voltage: 3.3V to 5V

*In-rush current control

*Bit-to-bit skew: ±3% Chip-to-chip skew: ±6%

*Package and pin assignment compatible to conventional LED drivers

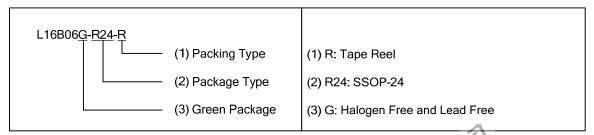
■ APPLICATIONS

*Indoor/Outdoor LED Video Display

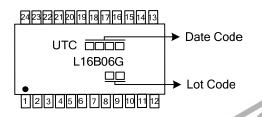
*LED Variable Message Signs (VMS) System

■ ORDERING INFORMATION

Ordering Number	Package	Packing
L16B06G-R24-R	SSOP-24	Tape Reel

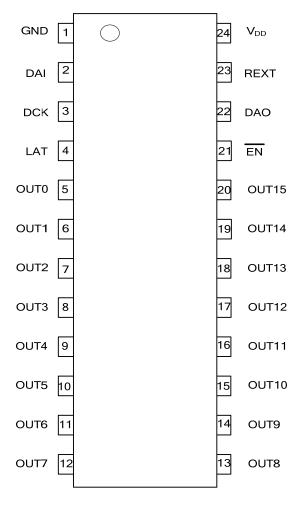


■ MARKING



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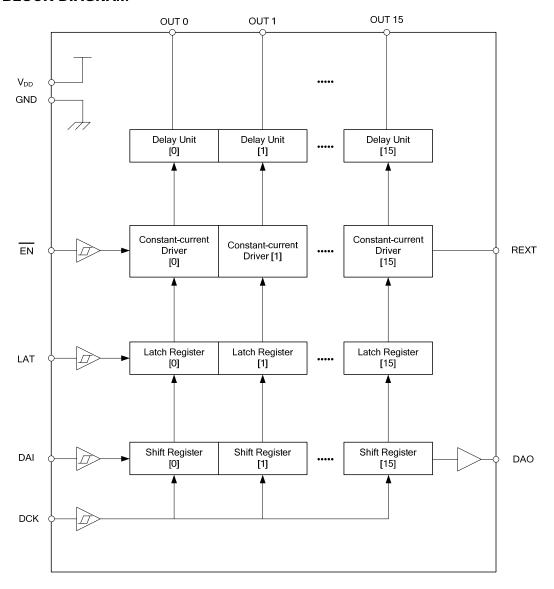
PIN CONNECTION



PIN DESCRIPTION

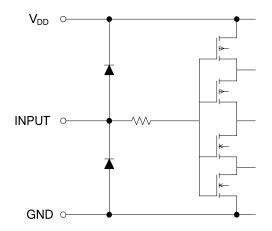
PIN No.	PIN NAME	FUNCTION
1	GND	Ground terminal.
2	DAI	Serial data input terminal.
3	DCK	Synchronous clock input terminal for serial data transfer. Data is sampled at the rising edge of DCK.
4	LAT	Input terminal of data strobe. Data on shift register goes through at the high level of LAT (level trigger). Otherwise, data is latched.
5-20	OUT0-15	Sink constant-current outputs (open-drain).
21	ĒN	Output enable terminal: 'H' for all outputs are turned off, 'L' for all outputs are active.
22	DAO	Serial data output terminal.
23	REXT	External resistors connected between REXT and GND for output current value setting.
24	V_{DD}	Supply voltage terminal.
		Supply voltage terminal. TECHNOLOGIES CO., LTD 2 of 13
UTC	UNISONIC www.unison	TECHNOLOGIES CO., LTD 2 of 13 QW-R502-A45.c

BLOCK DIAGRAM

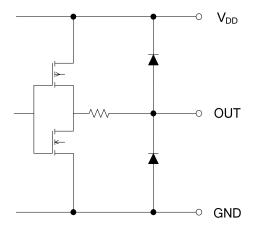


EQUIVALENT CIRCUIT OF INPUTS AND OUTPUTS

1. DCK, DAI, LAT, EN TERMINALS



2. DAO TERMINALS



■ MAXIMUM RATINGS (T_A=25°C, T_J=150°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{DD}	-0.3 ~ 7.0	٧
Input Voltage	V_{IN}	-0.3 ~ VDD+0.3	V
Output Current	I _{OUT}	70	mA
Output Voltage	V_{OUT}	-0.3 ~ 17	V
Input Clock Frequency	F _{DCK}	25	MHz
Operating Temperature	T _{OPR}	-40 ~ 85	ç
Storage Temperature	T _{STG}	-55 ~ 150	ç

■ RECOMMENDED OPERATING CONDITION

CHARACTERISTIC	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Supply Voltage	V_{DD}		3.3	5.0	5.5	V
Output Voltage	V _{OUT}	Driver On	1.0		0.5×V _{DD}	V
Output Voltage	V _{out}	Driver Off			17	V
Output Current	Io	OUTn	5		60	mA
Input Voltage	V _{IH}		0.8×V _{DD}		V_{DD}	V
Input Voltage	V _{IL}	V _{DD} =3.3V ~ 5.5V	0.0		0.2× _{VDD}	V

■ ELECTRICAL CHARACTERISTICS (V_{DD}=5.0 V, T_A=25°C, unless otherwise specified)

CHARACTERISTIC	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Input Voltage "H" Level	V_{IH}	CMOS Logic Level	0.8×V _{DD}		V_{DD}	V
Input Voltage "L" Level	V _{IL}	CMOS Logics2 Level	GND		0.2×V _{DD}	V
Output Leakage Current	l _{OL}	V _{OH} =17V			±1	μΑ
Output Voltage (DAO)	V _{OL}	I _{OL} =1.5mA			0.2	V
Output Voltage (DAO)	V _{OH}	I _{OH} =1.4mA	V _{DD} -0.2			V
Output Current Skew (Channel-to-Channel)	I _{OL1}	V _{OUT} =1.0V,			±3	%
Output Current Skew (Chip-to-Chip)	I _{OL2}	R _{REXT} =2.2KΩ			±6	%
Output Voltage Regulation	% / V _{OUT}	R_{REXT} =2.2K Ω , V_{OUT} =1V ~ 3V		±0.1	±0.5	%/V
Supply Voltage Regulation	% / V _{DD}	R _{REXT} =2.2KΩ		±1	±4	%/V

■ ELECTRICAL CHARACTERISTICS(Cont.)

CHARACTERISTIC	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT		
Supply Current	I _{DD(OFF)}	power on all pins are open unless V _{DD} and GND		3	4	mA		
	I _{DD(OFF)}	input signal is static Rrext=2.9KΩall outputs turn off		5	6	mA		
	I _{DD(ON)}	input signal is static Rrext=2.9KΩall outputs turn on		5	6	mA		
	I _{DD(OFF)}	input signal is static Rrext=1.05KΩall outputs turn off	PRIV	000	10	mA		
	I _{DD(ON)}	input signal is static Rrext=1.05KΩall outputs turn on	1680	9	10	mA		
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T TOTAL LINISONIC TECHNOL	OCIES CO.	TD				5 of 12		

SWITCHING CHARACTERISTICS (V_{DD}=5.0V, T_A=25°C, unless otherwise specified)

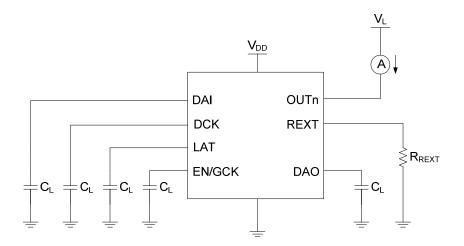
CHARACTE	RISTIC	SYMBOL	CONDITION	MIN	TYP	MAX	UNIT
Propagation Delay ('L' to 'H') Propagation Delay	EN-to-OUT0				52		ns
	LAT-to-OUT0	t _{PLH}			49		ns
	DCK-to-DAO				20		ns
	EN-to-OUT0	t _{PHL}			22		ns
	LAT-to-OUT0		$V_{IH}=V_{DD,}V_{IL}=GND$		75		ns
('H' to 'L')	DCK-to-DAO		$R_{REXT}=2.2k\Omega$,		19.5		ns
Output Current Rise Time		t _{OR}	V _L =5.0V, C _L =13pF		33.5		ns
Output Current Fall Time		t _{OF}			6		ns
Output Delay Time (OUT(n)-to-OUT(n+1))		t _{OD}			5		ns

$\textbf{SWITCHING CHARACTERISTICS} \text{ (V}_{DD}\text{=}3.3\text{V, T}_{A}\text{=}25^{\circ}\text{C, unless otherwise specified)}$

CHARACTI	ERISTIC	SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Dranagation Dalay	EN-to-OUT0				51		ns
Propagation Delay ('L' to 'H')	LAT-to-OUT0	t _{PLH}			21.5		ns
(L 10 H)	DCK-to-DAO				12		ns
Propagation Delay	EN-to-OUT0		V V V OND		23		ns
	LAT-to-OUT0	t _{PHL}	$V_{IH}=V_{DD}, V_{IL}=GND$ $R_{REXT}=2.2K\Omega$		49		ns
('H' to 'L')	DCK-to-DAO		V _L =5.0V, C _L =13pF		11.5		ns
Output Current Rise Time		t _{OR}	VL-3.0V, OL-13pi		35		ns
Output Current Fall Time		t _{OF}			10		ns
Output Delay Time (OUT(n)-to-OUT(n+1))		t _{OD}			10		ns



SWITCHING CHARACTERISTICS(Cont.)

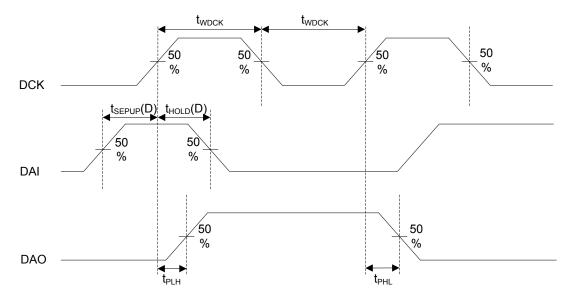


Switching Characteristics Test Circuit

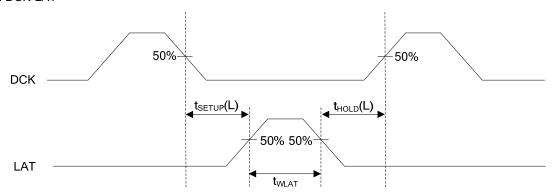


TIMING DIAGRAM

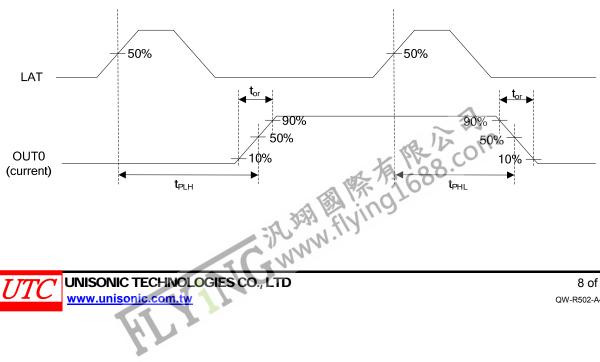
1. DCK-DAI, DAO



2. DCK-LAT

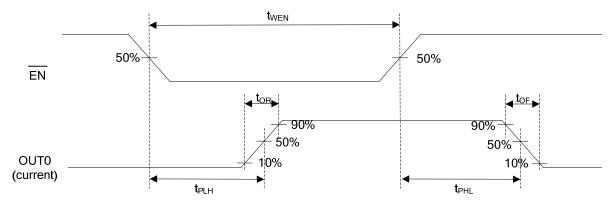


3. LAT-OUT0

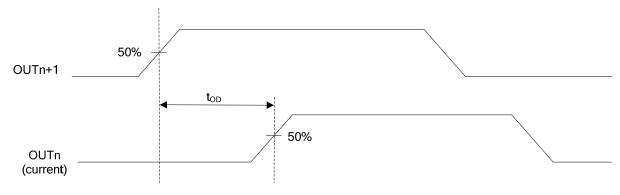


■ TIMING DIAGRAM(Cont.)

4. EN -OUT0



5. OUTn+1-OUTn



■ CONSTANT-CURRENT OUTPUT

Constant-current value of each output channel is set by an external resistor connected between the REXT pin an GND. Varying the resistor value can adjust the current scale ranging from 3mA to 60mA. The reference voltage of REXT terminal (Vrext) is approximately 1.2V. The output current value is calculated roughly by the following equation:

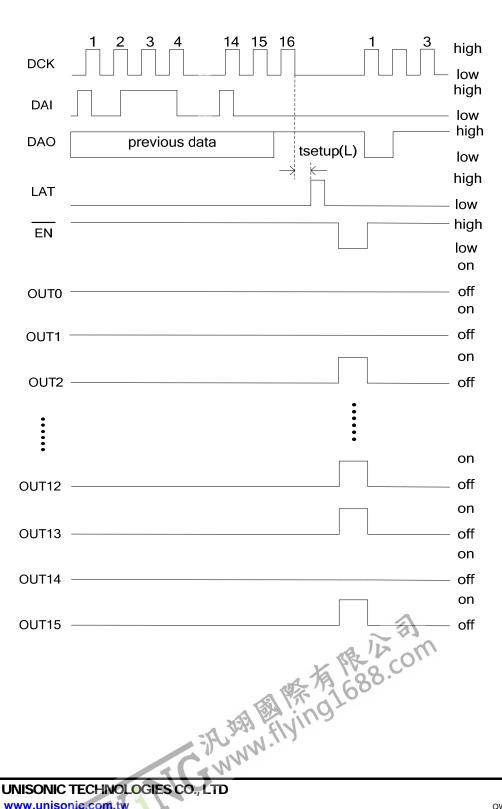
$$\mathsf{Iout}(mA) \cong \frac{V_{\mathsf{REXT}}(V)}{R_{\mathsf{REXT}}(K\Omega)} \times M$$

lout(mA)	3	5	10	20	30	40	50
М	55	54.1	50	46.6	45	43.3	41.6s

In order to obtain a good performance of constant-current output, a suitable output voltage is necessary.

SERIAL DATA INTERFACE

The serial-in data (DAI) will be clocked into 16 bit shift register synchronized on the rising edge of the clock (DCK). The data '1' represents the corresponding current output 'ON', while the data '0' stands for 'OFF'. The data will be transferred into the 16 bit latch register when the strobe signal (LAT) is 'H' (level trigger); otherwise, the data will be held. The trigger timing of the serial-out data (DAO) will be shifted out on synchronization to the rising edge of the clock. All outputs are turned off while enable terminal (EN) is kept at high level. And they are active when EN shifts to low.

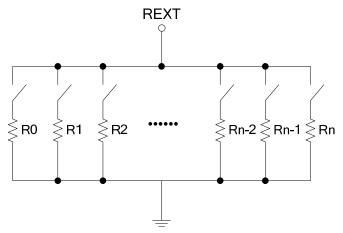


■ OUTPUTS DELAY

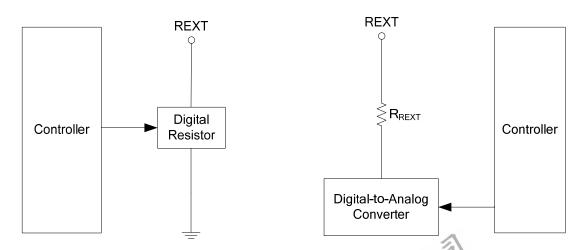
Large in-rush currents will occur when the system activates all the outputs at once. To reduce this effect, **L16B06** is designed to have a constant unit of delay (around 5ns) between outputs. The delay sequence for every output goes like this: OUT0 (no delay) \rightarrow OUT15 \rightarrow OUT1 \rightarrow OUT14 \rightarrow OUT2 \rightarrow OUT13 \rightarrow OUT3 \rightarrow OUT12 \rightarrow OUT14 \rightarrow OUT11 \rightarrow OUT5 \rightarrow OUT10 \rightarrow OUT6 \rightarrow OUT9 \rightarrow OUT7 \rightarrow OUT8 (the largest delay).

■ GLOBAL BRIGHTNESS CONTROL

L16B06 has no built-in global brightness control feature. In order to obtain a lower resolution of global brightness control effect, two methods could be utilized. One is providing PWM signal synchronized on latch pulse to modulate the output enable terminal ($\overline{\text{EN}}$ pin). The other is to adjust the R_{REXT} value or voltage drop across the external resistor. Please see the reference circuit below:



Global Brightness Control with Resistor Ladder



Global Brightness Control with Digital Resistor

Global Brightness Control with D/A Converter

■ POWER DISSIPATION

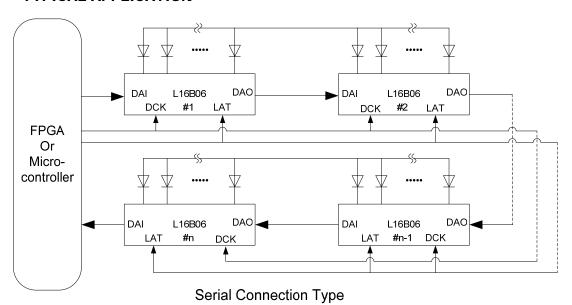
The power dissipation of a semiconductor chip is limited to its package and ambient temperature, in which the device requires the maximum output current calculated for given operating conditions. The maximum allowable power consumption can be calculated by the following equation:

$$P_{D}(max)(watt) = \frac{T_{J} \text{ (Junction temperature)}(max)(^{\circ}C) - T_{A}(Ambient Temperature)}{R_{TH} \text{ (Junction - to - air thermal resistance)}(^{\circ}C/watt)}$$

The power consumption of IC can be determined by the following equation an should be less than the maximum allowable power dissipation:

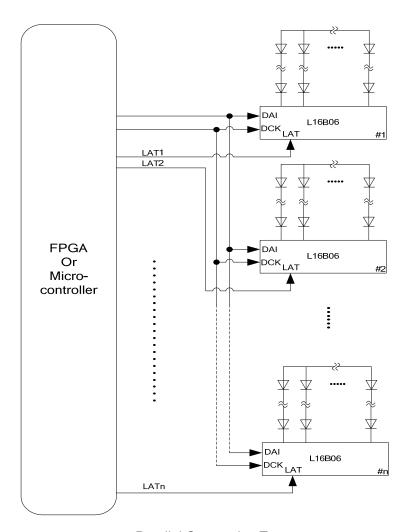
$$P_D(W) = V_{CC}(V) \times I_{DD}(A) + V_{OUT} \times I_{OUT} \times I$$

■ TYPICAL APPLICATION





■ TYPICAL APPLICATION(Cont.)



Parallel Connection Type

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